BC847 series

45 V, 100 mA NPN general-purpose transistors

Rev. 12 — 24 October 2019

Product data sheet

1. Product profile

1.1. General description

NPN general-purpose transistors in a small SOT23 (TO-236AB), very small SOT323 (SC-70) or ultra small SOT883 (DFN1006-3) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number[1]	Package			PNP complement	
	Nexperia	JEITA	JEDEC		
BC847	SOT23	-	TO-236AB	BC857	
BC847A	7			BC857A	
BC847B				BC857B	
BC847C				BC857C	
BC847W	SOT323	SC-70	-	BC857W	
BC847AW				BC857AW	
BC847BW				BC857BW	
BC847CW				BC857CW	
BC847AM	SOT883	SC-101	- 7	BC857AM	
BC847BM				BC857BM	
BC847CM				BC857CM	

[1] Valid for all available selection groups.

1.2. Features and benefits

- General-purpose transistors
- SMD plastic packages
- Three different gain selections
- AEC-Q101 qualified



1.3. Applications

· General-purpose switching and amplification



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1.4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	45	V
I _C	collector current		-	-	100	mA
h _{FE}	DC current gain	V _{CE} = 5 V;	110	-	800	
	h _{FE} group A	I _C = 2 mA	110	180	220	
	h _{FE} group B		200	290	450	
	h _{FE} group C		420	52 0	800	

2. Pinning information

Table 3. Pinning information

Pin	Symbol	Descrition	Simlified outline	Graphic symbol
SOT23; SOT323				
1	В	base	3	С
2	E	emitter		в
3	C	collector		
				Ė
			1 2	sym123
SOT883				
1	В	base	1	C
2	E	emitter	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	В
3	C	collector	Transparent	
			top view	Ē
				sym123



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3. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
BC847	TO-236AB	plastic surface-mounted package; 3	SOT23			
BC847A		leads				
BC847B						
BC847C						
BC847W	SC-70		SOT323			
BC847AW						
BC847BW						
BC847CW						
BC847AM	SC-101	lesdless ultra small plastic package;	SOT 883			
BC847BM		3 solder lands; body 1.0 x 0.6 x 0.5 mm				
BC847CM						

4. Marking

Table 5. Marking codes

Type number		Marking code
BC847	[1]	1H%
BC847A	[1]	1E%
BC847B	[1]	1F%
BC847C	[1]	1G%
BC847W	[1]	1H%
BC847AW	[1]	1E%
BC847BW	[1]	1F%
BC847CW	[1]	1G%
BC847AM		D4
BC847BM		D5
BC847CM		D6

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[1] % = placeholder for manufacturing site code

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5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	45	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	100	mA
I _{CM}	peak collector current	single pulse; t _{p ≤ 1 ms}		-	200	mA
I _{BM}	peak base current	single pulse; t _{p ≤ 1 ms}		9,	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	7			
	SOT23		[1]	7	250	mW
	SOT323		[1]	-	200	mW
	SOT883		[2]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint. Device mounted on an PCB with 60 µm copper strip line, standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

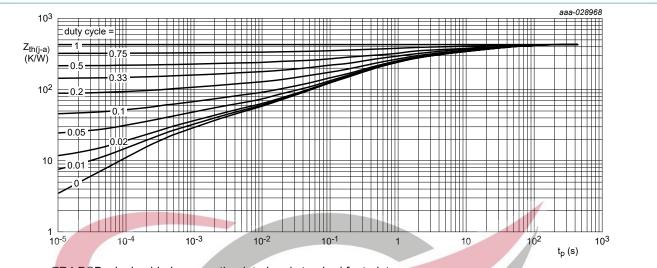
Symbol	Parameter	Conditions	1	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	4				
	SOT23		[1]	-	-	500	K/W
	SOT323		[1]	-	-	625	K/W
	SOT883		[2]	-	-	500	K/W

Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.

Device mounted on an PCB with 60 µm copper strip line, standard footprint.

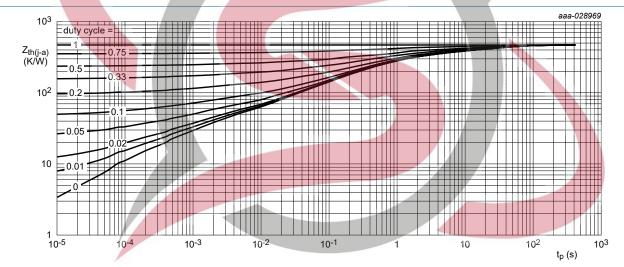


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FR4 PCB; single-sided copper; tin-plated and standard footprint

Fig. 1. SOT23: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated and standard footprint

Fig. 2. SOT323: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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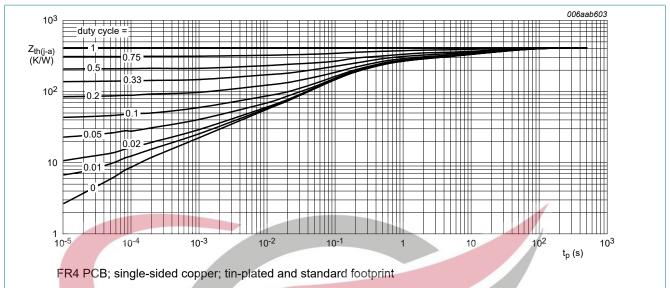


Fig. 3. SOT883: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



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7. Characteristics

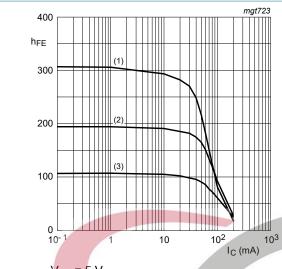
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A		50	-	-	V
$V_{(BR)CES}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; V_{BE} = 0 \text{ A}$		45	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I _C = 0 A; I _E = 100 μA		6	-	-	V
I _{CBO}	collector-base	$V_{CB} = 30 \text{ V}; I_{E} = 0 \text{ A}$		-	-	15	nA
	cut-off current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$			-/	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	7	100	nA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \mu\text{A}$					
	h _{FE} group A			-	170	-	
	h _{FE} group B			-	280	-	
	h _{FE} group C			-	420	-	
	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$		110	-	800	
	h _{FE} group A		11	110	180	220	
	h _{FE} group B			200	290	450	
	h _{FE} group C			420	520	800	
V_{CEsat}	collector-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$		-/	90	200	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[1]	-	200	400	mV
V_{BEsat}	base-emitter saturation	I _C = 10 mA; I _B = 0.5 mA	[2]	-	700	-	mV
	voltage	I _C = 100 mA; I _B = 5 mA	[2]	-	900	-/	mV
V_{BE}	base-emitter voltage	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$	[2]	580	660	700	mV
		$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$		-	-	770	mV
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz}$		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$				1.5	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = I_C = 0 \text{ A}; f = 1 \text{ MHz}$		-	11	7	pF
NF	noise figure	I_C = 200 μA; V_{CE} = 5 V; R_S = 2 kΩ; f = 1 kHz; B = 200Hz			2	10	dB

[1] pulsed; t_p ≤ 300 μs; δ ≤ 0.02 [2] V_{BE} decreases by approximately 2 mV/K with increasing temperature

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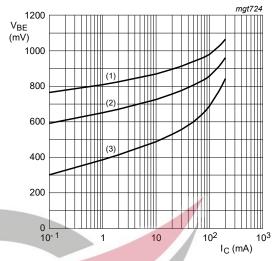
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. Group A: DC current gain as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. Group A: Base-emitter voltage as a function of collector current; typical values

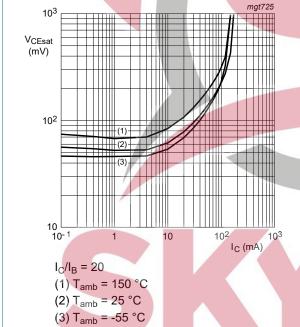
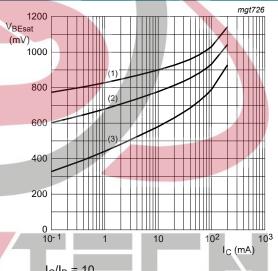


Fig. 6. Group A: Collector-emitter saturation voltage as Fig. 7. a function of collector current; typical values



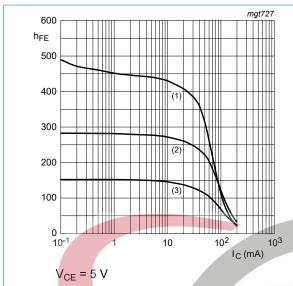
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

Group A: Base-emitter saturation voltage as a function of collector current; typical values

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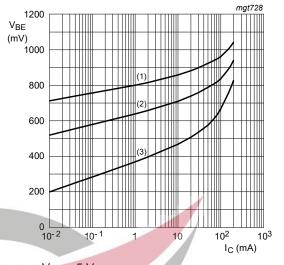


$$(1) T_{amb} = 150 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Group B: DC current gain as a function of Fig. 8. collector current; typical values



$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Group B: Base-emitter voltage as a function of Fig. 9. collector current; typical values

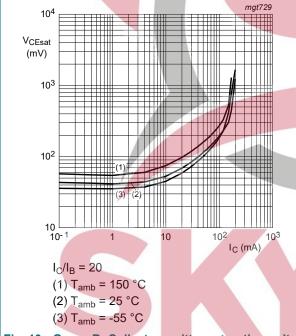
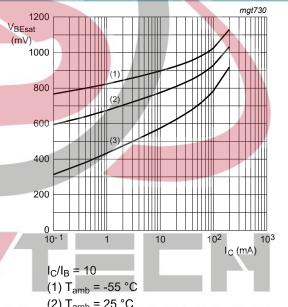
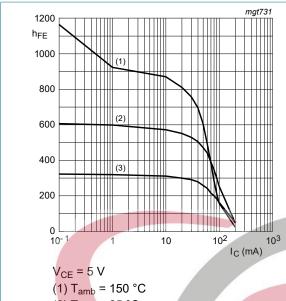


Fig. 10. Group B: Collector-emitter saturation voltage as Fig. 11. a function of collector current; typical values



Group B: Base-emitter saturation voltage as a function of collector current; typical values

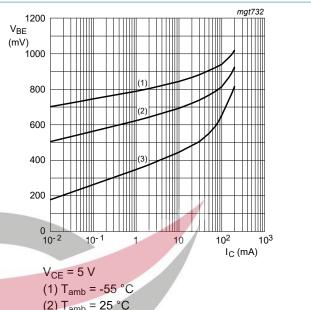
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$$(2) T_{amb} = 25 °C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. Group C: DC current gain as a function of collector current; typical values



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. Group C: Base-emitter voltage as a function of collector current; typical values

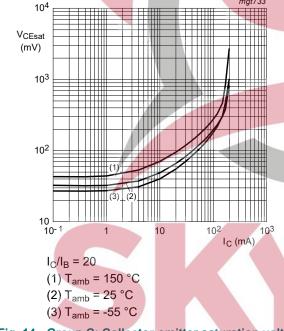
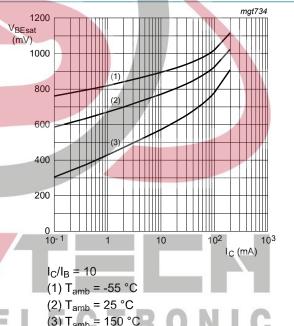


Fig. 14. Group C: Collector-emitter saturation voltage as Fig. 15. a function of collector current; typical values



(3) $T_{amb} = 150 \, ^{\circ}C$

Group C: Base-emitter saturation voltage as a function of collector current; typical values

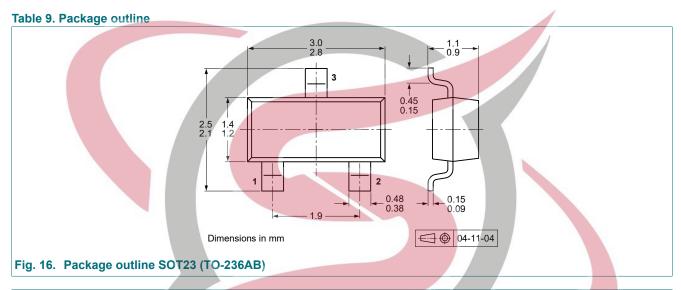
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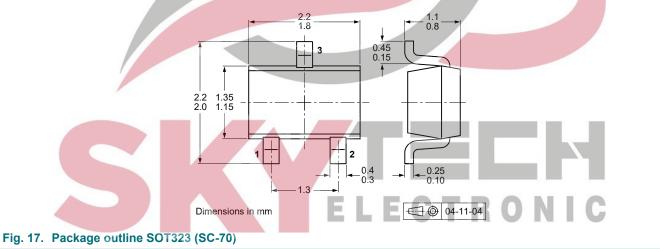
8. Test information

8.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

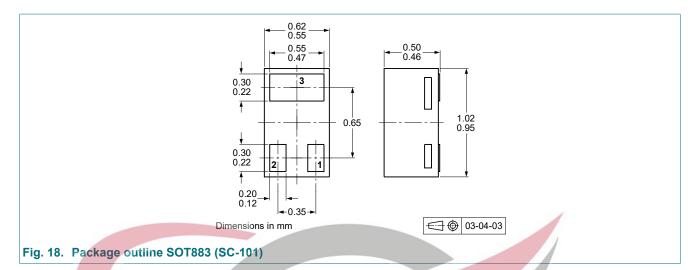
9. Package outline





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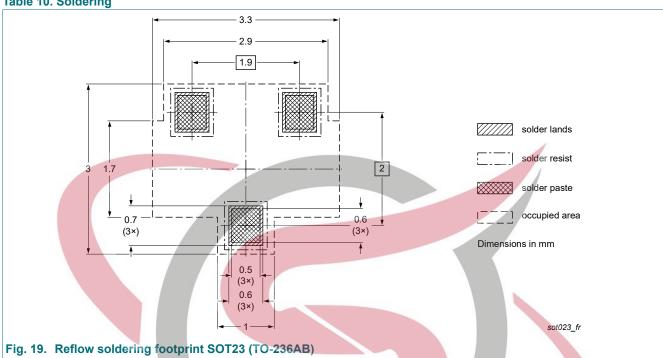


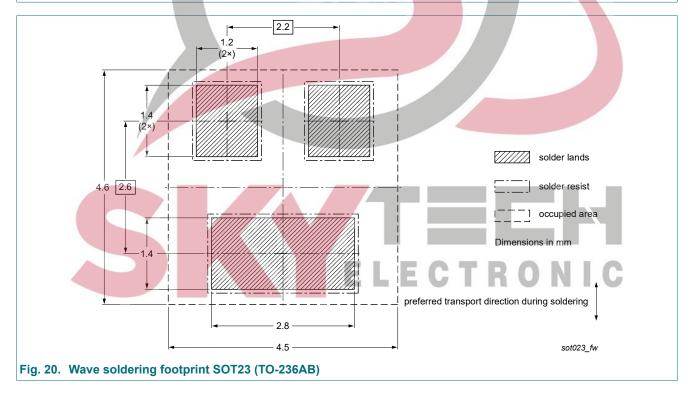


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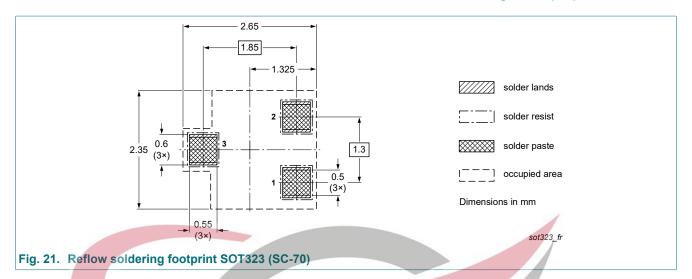
10. Soldering

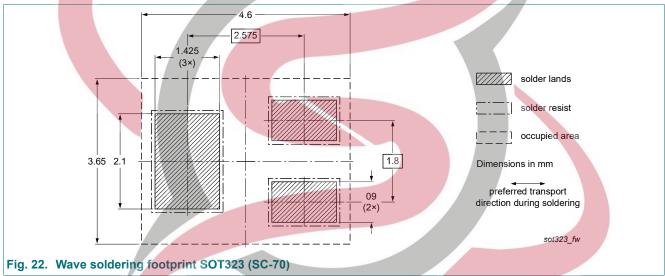
Table 10. Soldering

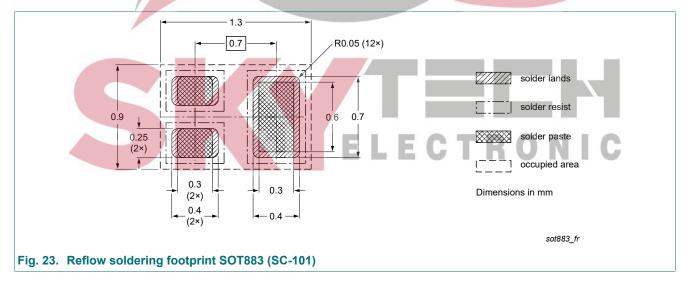




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11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC847_SER v.12	20191024	Product data sheet	-	BC847_SER v.11
Modifications:	Table 1: He	ader NPN complement correcte	d to PNP con	nplement
BC847_SER v.11	20181205	Product data sheet	-	BC847_SER v.10
BC847_SER v.10	20180302	Product data sheet	-	BC847_SER v.9
BC847_SER v.9	20140923	Product data sheet	-	BC847_SER v.8
BC847_SER v.8	20120820	Product data sheet	-	BC847_BC547_SER v.7
BC847_BC547_SER v.7	20081210	Product data sheet	-	BC847_BC547_SER v.6
BC847_BC547_SER v.6	20050519	Product data sheet	-	



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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